

APW-MW2-1210-010

Surface Mount Dual Emitter LEDs

The APW-MW2-1210-010 is a two drive line dual emitter oximeter component. The 660nm and 940nm GaAlAs infrared emitters are mounted in a “glob top” ceramic 1210 SMT package.

Applications

Oximeter Probes

Finger Clamps

Reusable Probes

Features

660 nm \pm 3 nm

940 nm \pm 10 nm

Optimal Peak Wavelength Binning

Two Drive Lines

Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
Continuous Forward Current	-	-	30	mA
Peak Forward Current	-	-	200	mA
Power Dissipation	-	-	250	mW
Operating Temperature	T_{OP}	-40	+80	°C
Storage Temperature	T_{STG}	-40	+80	°C
Package		1210		

660nm Typical Electro-Optical Specifications at $T_A=23\text{ °C}$

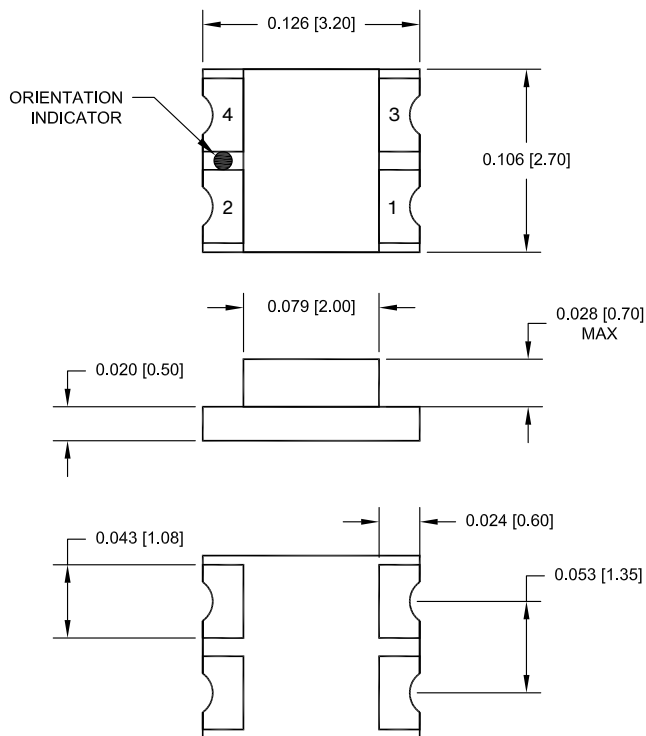
Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Breakdown Voltage	$I_f=10\mu\text{A}$	V_{BD}	5	-	-	V
Radiant Flux	$I_f=20\text{mA}$	Φ_e	-	9.5	-	mW
Luminous Intensity	$I_f=20\text{mA}$	I_v	-	180	-	mcd
Forward Voltage	$I_f=20\text{mA}$	V_F	-	1.94	2.30	V
Peak Wavelength	$I_f=20\text{mA}$	λ_p	657	660	663	nm
Rise Time (50Ω load)	$I_f=20\text{mA}$	t_r	-	15	-	ns
Fall Time	$I_f=20\text{mA}$	t_f	-	15	-	ns
Spectral Halfwidth	$I_f=20\text{mA}$	$\Delta\lambda$	-	20	-	nm

940nm Typical Electro-Optical Specifications at $T_A=23\text{ °C}$

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Breakdown Voltage	$I_f=10\mu\text{A}$	V_{BD}	5	-	-	V
Radiant Flux	$I_f=20\text{mA}$	Φ_e	-	5	-	mW
Forward Voltage	$I_f=20\text{mA}$	V_F	-	1.5	1.65	V
Peak Wavelength	$I_f=20\text{mA}$	λ_p	930	940	950	nm
Rise Time (50Ω load)	$I_f=20\text{mA}$	t_r	-	15	-	ns
Fall Time	$I_f=20\text{mA}$	t_f	-	15	-	ns
Spectral Halfwidth	$I_f=20\text{mA}$	$\Delta\lambda$	-	50	-	nm

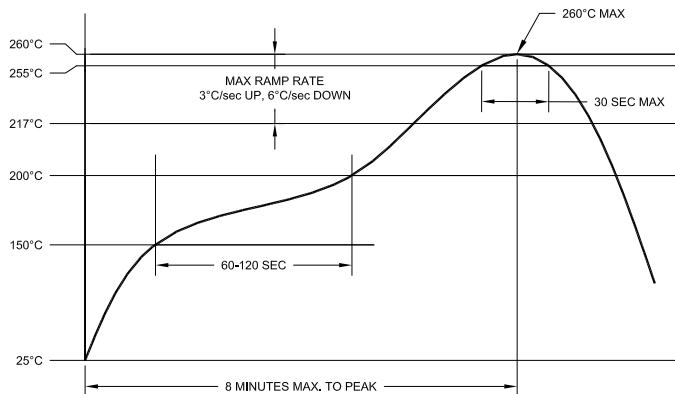
Mechanical Specifications

Units are in inches (mm)



Pin Out	
1	600nm Cathode
2	600nm Anode
3	940nm Cathode
4	940nm Anode

Reflow Profile



Soldering

Recommendation		
Wave	Not Advised	-
IR Oven Reflow	Allowed	See Reflow Profile
Forced Convection Reflow	Recommended	See Reflow Profile
Convection Reflow	Recommended	See Reflow Profile
Vapor Phase Reflow	Recommended	See Reflow Profile
Manual	Not Advised	260°C for 3 seconds max
Moisture Sensitivity Level	2	J-STD-033

Care and handling instructions

Your optoelectronic components are packaged and shipped in opaque, padded containers to avoid ambient light exposure and damage due to shock from dropping or jarring.

Care must be taken to avoid exposure to high ambient light levels, particularly from tungsten sources or sunlight.

- These components can be rendered inoperable if dropped or sharply jarred. The wire bonds are delicate and can become separated from the bonding pads when the component is dropped or otherwise receives a sharp physical blow.
- Most windows on photodiodes are either silicon or quartz. They should be cleaned with isopropyl alcohol and a soft (optical grade) pad.
- Photodiode exposure to extreme high or low storage temperatures can affect the subsequent performance. Maintain a non-condensing environment for optimum performance and lifetime.
- All devices are considered ESD sensitive. The photodiodes are shipped in ESD protective packaging. When unpacking and using these products, anti-ESD precautions should be observed.
- Photodiode packages and/or operation may be impaired if exposed to CHLOROETHENE, THINNER, ACETONE, TRICHLOROETHYLENE or any harsh chemicals.
- Optoelectronic components in plastic packages should be given special care. Clear plastic packages are more sensitive to environmental stress than those of black plastic. Storing devices in high humidity can present problems when soldering. Since the rapid heating during soldering stresses the wire bonds and can cause wire to bonding pad separation, it is recommended that devices in plastic packages to be baked for 24 hours at 85°C.
- The leads on the photodiode SHOULD NOT BE FORMED. If your application requires lead spacing modification, please contact Advanced Photonix Applications group at Techsupport@advancedphotonix.com before forming a product's leads. Product warranties could be voided.
- Most devices are provided with wire or pin leads for installation in circuit boards or sockets. Observe the soldering temperatures and conditions specified below:
 - Soldering Iron: Soldering 30 W or less
 - Temperature at tip of iron 300°C or lower.
 - Dip Soldering: Bath Temperature: 260±5°C.
 - Immersion Time: within 5 Sec.
 - Soldering Time: within 3 Sec.
 - Vapor Phase Soldering, Reflow Soldering: DO NOT USE

Legal Disclaimer

Information in this data sheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.



Most of our standard catalog products are RoHS Compliant. Please contact us for details.

